# NSN 5961-01-382-7610

Transistor - Page 1 of 1



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## Internal Configuration:

Junction contact

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

16.0 collector-to-emitter, substaining voltage, base open-circuited and 36.0 collector to base voltage/static/emitter open and 4.0 emitter to

base voltage, static, collector open

#### **Current Rating Per Characteristic:**

400.00 milliamperes source cutoff current

# Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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